

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|--------------|--|------------------|--------------|------|
| Drain-Source Voltage | | | V _{DSS} | -12 | V |
| Gate-Source Voltage | | | V _{GSS} | -5 | V |
| Continuous Drain Current (Note 5) V _{GS} = -4.5V | Steady State | T _A = +25°C T _A = +70°C | I _D | -2.6 -2.1 | A |
| Continuous Drain Current (Note 5) V _{GS} = -2.5V | Steady State | T _A = +25°C T _A = +70°C | I _D | -2.4 -1.9 | A |
| Pulsed Drain Current (Note 6) | | | I _{DM} | -10 | A |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P _D | 0.82 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5) | R _{θJA} | 150 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|---------------------|------|------|------|------|---|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -12 | - | - | V | V _{GS} = 0V, I _D = -250μA |
| Gate-Source Breakdown Voltage | BV _{GSS} | -6.0 | - | - | V | V _{DS} = 0V, I _G = -250μA |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | - | - | -1 | μA | V _{DS} = -9.6V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | - | - | -500 | nA | V _{GS} = -5V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | -0.4 | -0.6 | -1.0 | V | V _{DS} = V _{GS} , I _D = -250μA |
| Static Drain-Source On-Resistance | R _{DS(on)} | - | 85 | 102 | mΩ | V _{GS} = -4.5V, I _D = -500mA |
| | | - | 97 | 116 | | V _{GS} = -2.5V, I _D = -500mA |
| | | - | 127 | 152 | | V _{GS} = -1.5V, I _D = -500mA |
| Forward Transfer Admittance | Y _{fs} | - | 4 | - | S | V _{DS} = -6V, I _D = -500mA |
| Diode Forward Voltage | V _{SD} | - | -0.6 | -1.0 | V | V _{GS} = 0V, I _S = -500mA |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C _{iss} | - | 251 | - | pF | V _{DS} = -6V, V _{GS} = 0V, f = 1.0MHz |
| Output Capacitance | C _{oss} | - | 359 | - | | |
| Reverse Transfer Capacitance | C _{rss} | - | 70 | - | | |
| Total Gate Charge | Q _g | - | 3.7 | - | nC | V _{GS} = -4.5V, V _{DS} = -6V, I _D = -500mA |
| Gate-Source Charge | Q _{gs} | - | 0.4 | - | | |
| Gate-Drain Charge | Q _{gd} | - | 0.6 | - | | |
| Gate Charge at V _{th} | Q _{g(th)} | - | 0.2 | - | | |
| Turn-On Delay Time | t _{D(on)} | - | 17.6 | - | ns | V _{DS} = -6V, V _{GS} = -2.5V, R _G = 20Ω, I _D = -500mA |
| Turn-On Rise Time | t _r | - | 26.9 | - | | |
| Turn-Off Delay Time | t _{D(off)} | - | 37.5 | - | | |
| Turn-Off Fall Time | t _f | - | 32.3 | - | | |

- Notes:
- Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
 - Repetitive rating, pulse width limited by junction temperature.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to production testing.

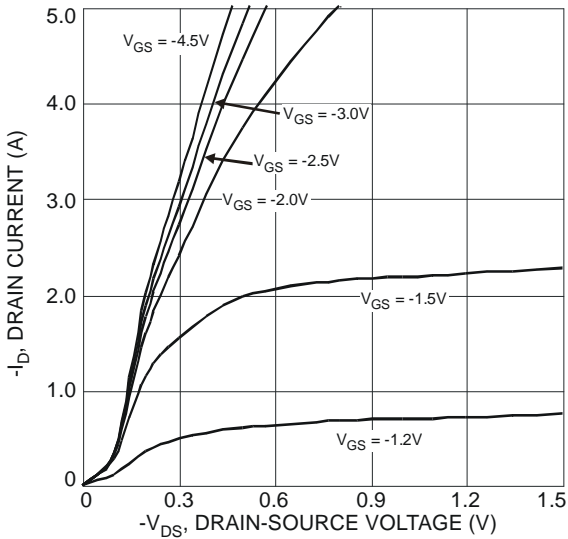


Fig. 1 Typical Output Characteristic

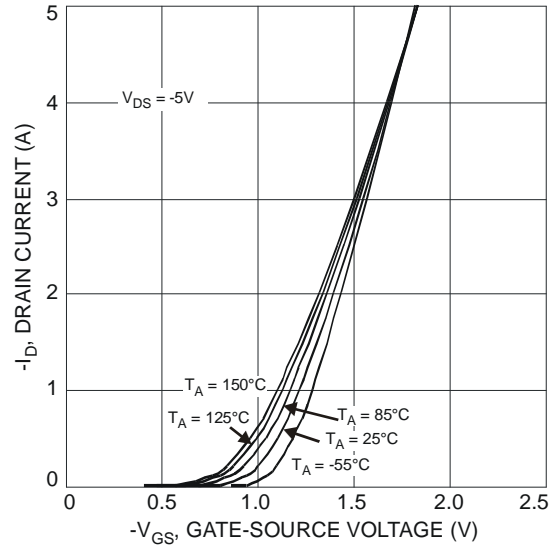


Fig. 2 Typical Transfer Characteristic

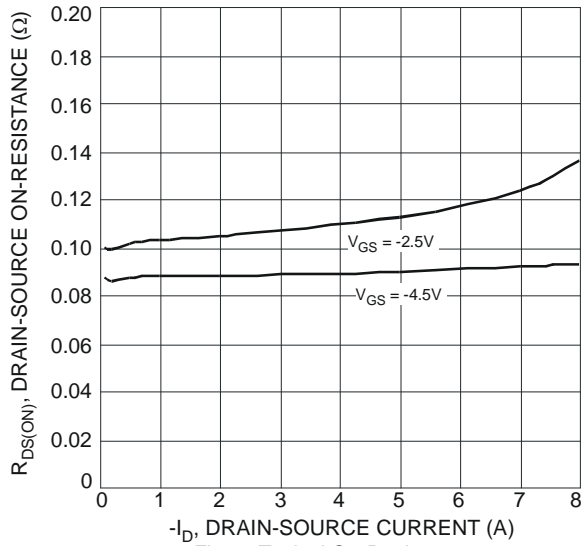


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

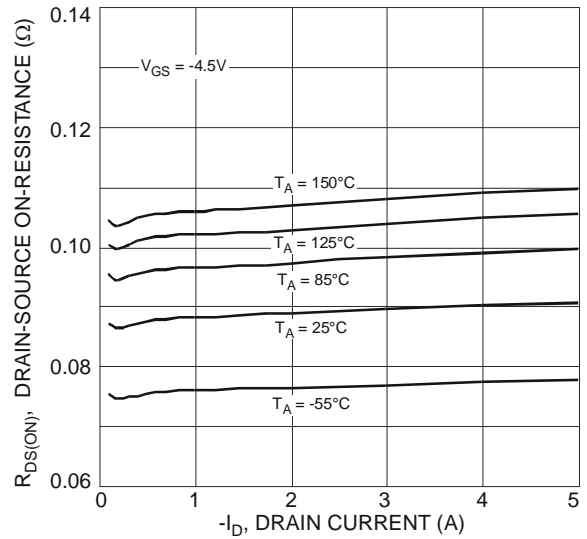


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

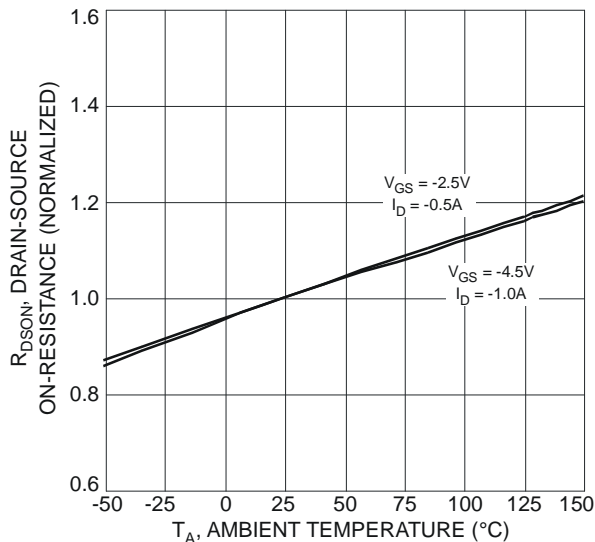


Fig. 5 On-Resistance Variation with Temperature

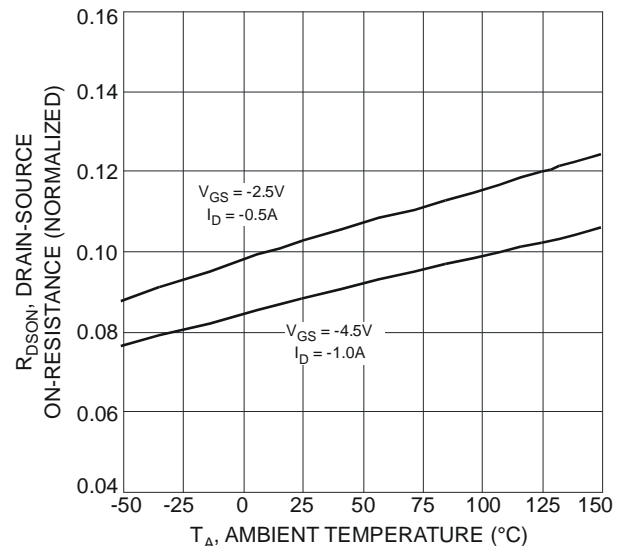


Fig. 6 On-Resistance Variation with Temperature

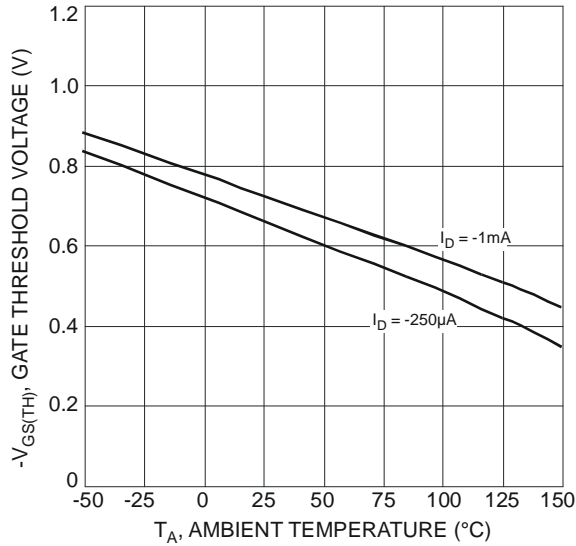


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

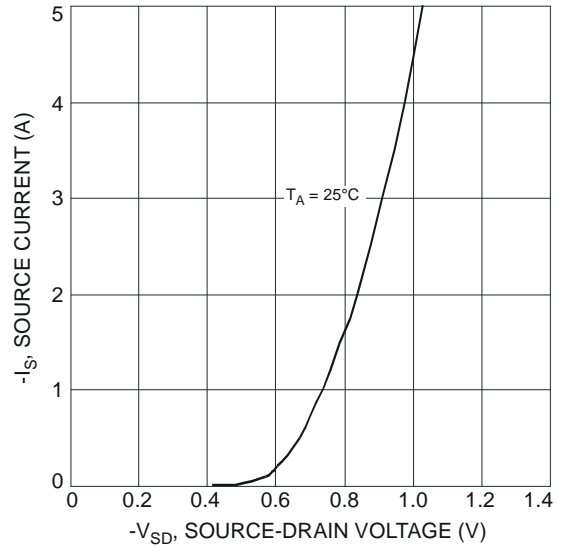


Fig. 8 Diode Forward Voltage vs. Current

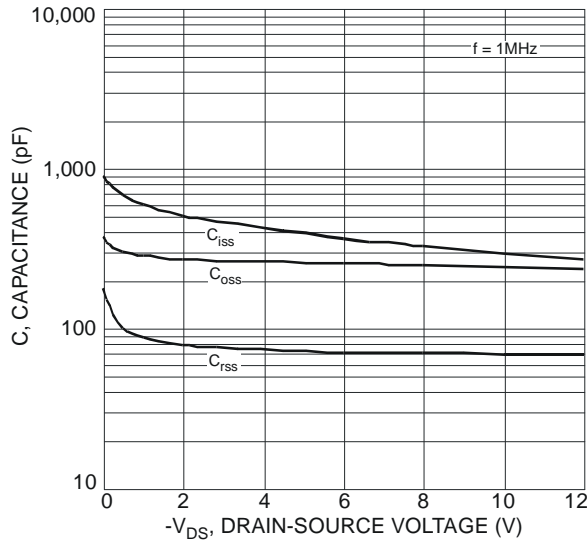


Fig. 9 Typical Total Capacitance

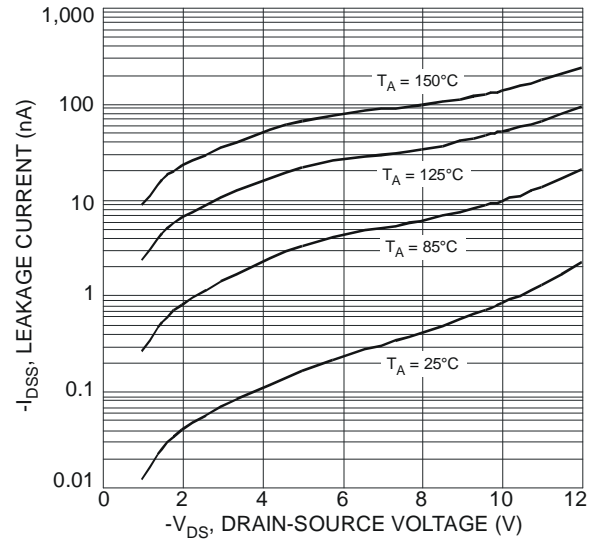


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

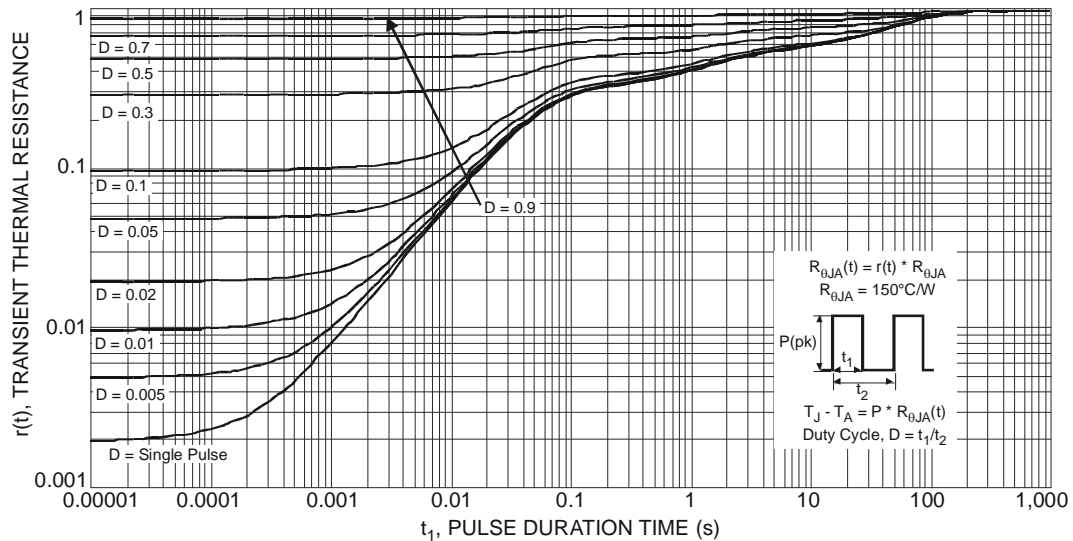
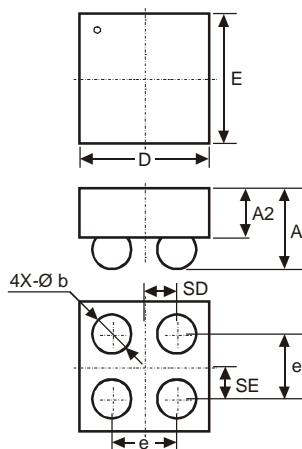


Fig. 11 Transient Thermal Response

Package Outline Dimensions

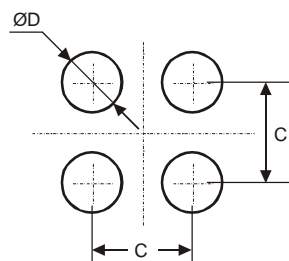
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| U-WLB1010-4 | | | |
|----------------------|------|------|------|
| Dim | Min | Max | Typ |
| D | 0.95 | 1.05 | 1.00 |
| E | 0.95 | 1.05 | 1.00 |
| A | — | 0.62 | — |
| A2 | — | — | 0.38 |
| b | 0.25 | 0.35 | 0.30 |
| e | — | — | 0.50 |
| SD | — | — | 0.25 |
| SE | — | — | 0.25 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.50 |
| D | 0.25 |

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